NSN 5962-01-169-2615

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View Online at https://aerobasegroup.com/nsn/5962-01-169-2615
Body Length:
Between 0.740 inches and 0.870 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.120 inches and 0.185 inches
Maximum Power Dissipation Rating:
794.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and monolithic and burn in and programmed and schottky and w/active pull-up and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Precious Material And Location:
Terminal surface option gold
Precious Material:
Gold
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
16 printed circuit
Shelf Life:

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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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